

**U.S. UTILITY** Patent Application

O.I.P.E.

PATENT DATE

SCANNED *11km 3 9A* ~~11km 3 9A~~

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/986445	F	438	500	2012-0829	GC-20

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## Method for fabricating a contact pad of semiconductor device

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PTO-2040  
12/02

## ISSUING CLASSIFICATION

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